

TOSHIBA

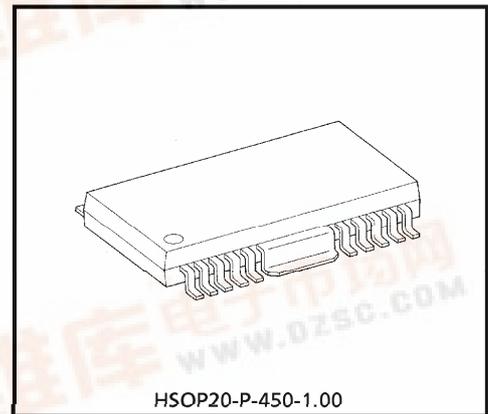
TA8529F

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT MULTI-CHIP PACKAGE

TA8529F

Stepping Motor Driver IC (TA8528 + 2SA950 × 4 MCP)

TA8529F is a stepping motor driver IC which operates based on bipolar transistors. The device incorporates stepping motor driver IC TA8528 and four PNP transistors 2SA950 configuring a multi-chip package. It also incorporates a standby function and two bridge drivers which enable an inductive load to be driven by the bipolar transistors. Four-port inputs allow driving by 1-phase excitation, 2-phase excitation, or 1/2-phase excitation. Selecting the mode enables two-port inputs which allows driving by 2-phase excitation. The device can be used as a low-saturation-voltage bridge driver.



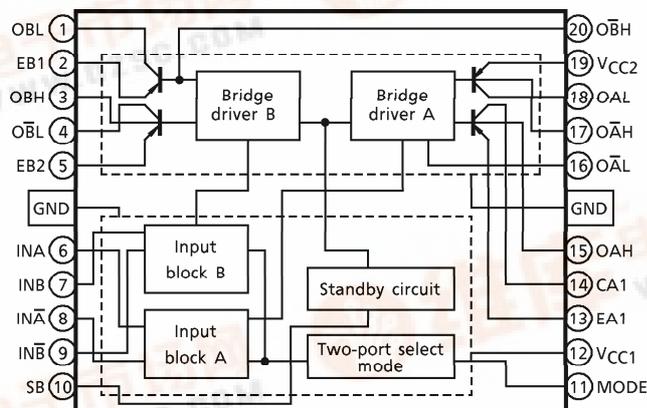
HSOP20-P-450-1.00

Weight : 0.79g (Typ.)

FEATURES

- Two low-saturation-voltage bridge drivers: saturation voltage < 0.95V (I_O = 400mA)
- 1-phase excitation, 2-phase excitation, 1/2-phase excitation enabled by four-port inputs (pin 11 open)
- 2-phase excitation enabled by two-port inputs (pins 8, 9, 11 grounded)
- Built-in standby function
- Built-in rush-current protector circuit for when switching excitation current
- Standard 20-pin PFP
- GND pin = heat sink

BLOCK DIAGRAM



961001EBA2

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● The information contained herein is subject to change without notice.



PIN FUNCTION

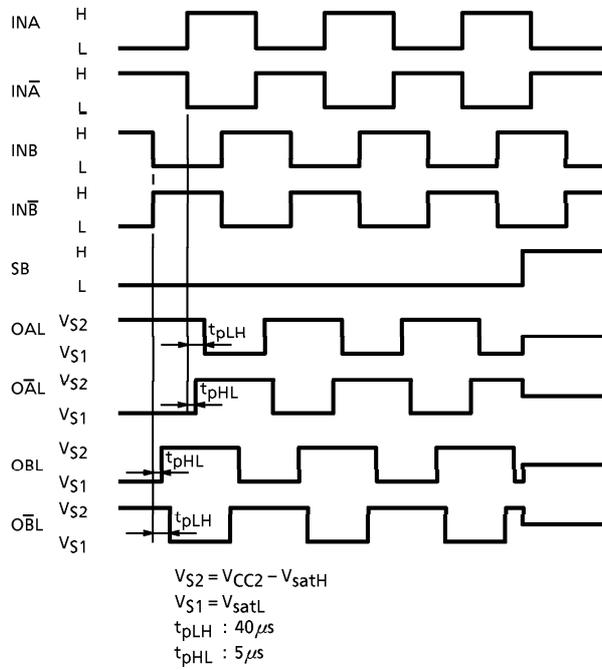
PIN No.	PIN NAME	FUNCTION	I/O
1	OBL	Bridge driver B output pin	O
2	EB1	PNP transistor emitter pin	—
3	OBH	PNP transistor base pin	—
4	O \bar{B} L	Bridge driver B output pin	O
5	EB2	PNP transistor emitter pin	—
6	INA	Channel A excitation input pin	I
7	INB	Channel B excitation input pin	I
8	IN \bar{A}	Channel A excitation input pin	I
9	IN \bar{B}	Channel B excitation input pin	I
10	SB	Standby function input pin	I
11	MODE	Two-port input select mode pin	I
12	V $_{CC1}$	5V supply pin	—
13	EA1	PNP transistor emitter pin	—
14	CA1	PNP transistor collector pin	—
15	OAH	PNP transistor base pin	—
16	O \bar{A} L	Bridge driver A output pin	O
17	O \bar{A} H	PNP transistor base pin	—
18	OAL	Bridge driver A output pin	O
19	V $_{CC2}$	5V / 12V supply pin	—
20	OBH	PNP transistor base pin	—
F	S.GND P.GND	Small signal ground pin Power ground pin	—

LOGIC CHART

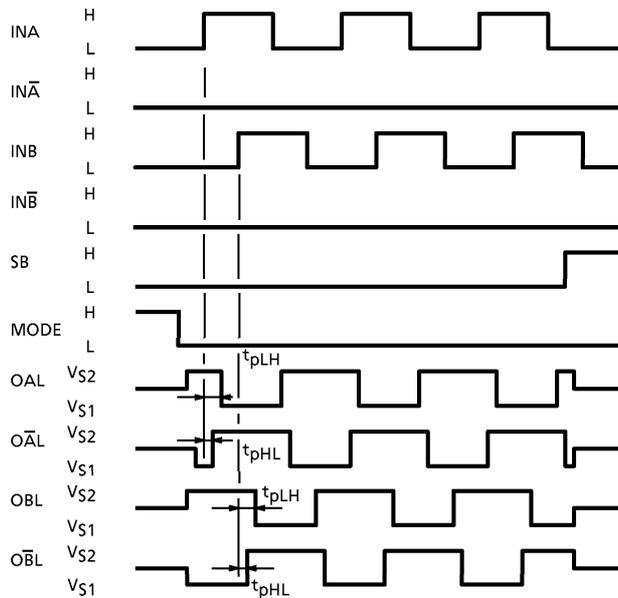
INPUT				OUTPUT		
SB	MODE	INA (B)	IN \bar{A} (\bar{B})	OA (B) L	O \bar{A} (\bar{B}) L	
L	H	L	L	∞	∞	OPERATION
L	H	H	H	∞	∞	OPERATION
L	H	H	L	L	H	OPERATION
L	H	L	H	H	L	OPERATION
L	L	L	L	H	L	OPERATION
L	L	H	L	L	H	OPERATION
H	X	X	X	∞	∞	STAND-BY

X : Don't Care
 ∞ : High impedance

TIMING CHART 1



TIMING CHART 2



MAXIMUM RATINGS (Ta = 25°C)

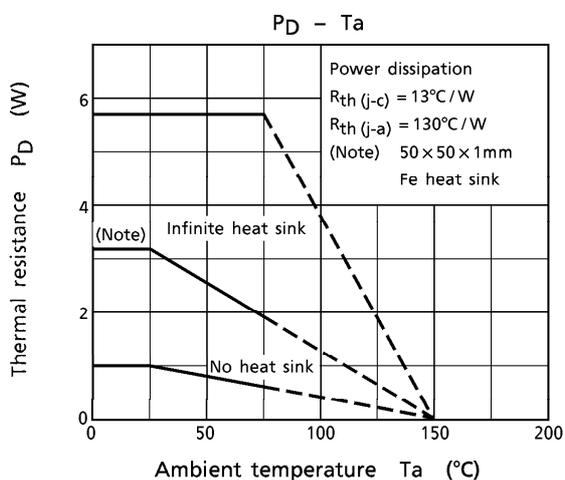
CHARACTERISTICS	SYMBOL	RATING	UNIT
Power supply voltage	V _{CC1}	7.0	V
	V _{CC2}	17.0	
Output current	I _O (MAX)	± 500	mA
Input voltage	V _{IN}	~V _{CC1}	V
Power dissipation	P _D	1.0	W
Operating temperature	T _{opr}	(Note) - 30~75	°C
Storage temperature	T _{stg}	- 55~150	°C

(Note) Depending on the operating temperature, output current may be restricted. (See Pd-Ta characteristics graph.)

RECOMMENDED OPERATING CONDITION

CHARACTERISTICS	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Power supply voltage	V _{CC1}	—	—	4.5	—	5.5	V
	V _{CC2}	—	—	4.5	—	13.2	

Package PFP-20 characteristics

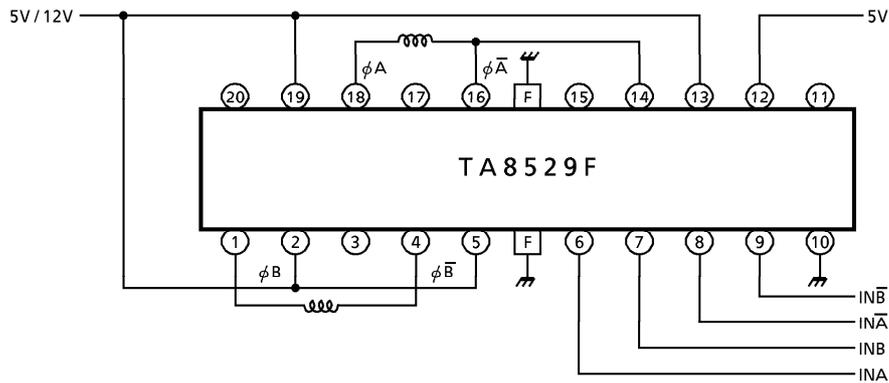


ELECTRICAL CHARACTERISTICS (Ta = 25°C, VCC1 = 5V, VCC2 = 12V)

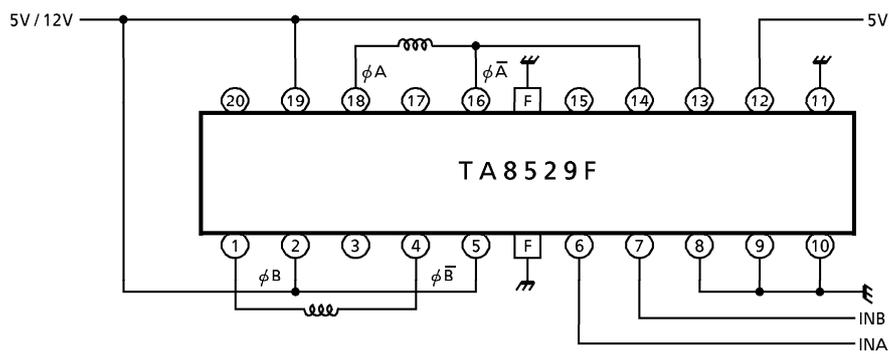
CHARACTERISTICS	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Supply Current	I _{CC1}	—	V _{SB} = 5V, output open	—	—	5	μA	
	I _{CC2}			—	—	10		
	I _{CC1}	—	V _{SB} = 5V, output open 1 input = 5V, 3 inputs = 0V	—	—	5	μA	
	I _{CC2}			—	—	10		
	I _{CC1}	—	V _{SB} = 5V, output open A : 1 input = 5V, B : 1 input = 5V A : 1 input = 0V, B : 1 input = 0V	—	—	5	μA	
	I _{CC2}			—	—	10		
	I _{CC1}	—	Output open, V _{SB} = 0V 1 input = 5V, 3 inputs = 0V	—	25	30	mA	
	I _{CC2}			—	20	25		
	I _{CC1}	—	Output open, V _{SB} = 0V A : 1 input = 5V, B : 1 input = 5V A : 1 input = 0V, B : 1 input = 0V	—	35	44	mA	
	I _{CC2}			—	35	47		
	I _{CC1}	—	Output open, V _{SB} = 0V V _{MODE} = 0V, input = 0V	—	35	44	mA	
	I _{CC2}			—	35	47		
Input Voltage	V _{INH}	—	Pins 6, 7, 8, and 9	2.0	—	V _{CC1}	V	
	V _{INL}			GND	—	0.8		
	V _{SBH}	—	Pin 10	3.5	—	V _{CC1}	V	
	V _{SBL}			GND	—	2.0		
	V _{MODEH}	—	Pin 11	3.5	—	V _{CC1}	V	
	V _{MODEL}			GND	—	2.0		
Input Current	I _{INH}	—	V _{IN} = 3.5V	Pins 6, 7, 8, and 9	—	-2	-10	μA
	I _{INL}	—	V _{IN} = 0.4V		—	-200	-300	
	I _{SBH}	—	V _{SB} = 3.5V	Pin 10	—	-30	-45	μA
	I _{SBL}	—	V _{SB} = 0.4V		—	-150	-220	
Saturation voltage (Note) V _{sat1} = V _{satH1} + V _{satL1} V _{sat2} = V _{satH2} + V _{satL2}	V _{satH1}	—	I _O = 100mA	—	0.1	—	V	
	V _{satH2}	—	I _O = 400mA	—	0.15	—		
	V _{satL1}	—	I _O = 100mA	—	0.1	—	V	
	V _{satL2}	—	I _O = 400mA	—	0.45	—		
	V _{sat1}	—	I _O = 100mA	—	0.2	0.4	V	
	V _{sat2}	—	I _O = 400mA	—	0.6	0.95		
Diode Forward Voltage	V _F	—	I _F = 400mA	—	1.4	1.6	V	
Delay time During	t _{pLH}	—	IN-φ	—	40	—	μs	
	t _{pHL}			—	5	—		

APPLICATION CIRCUIT

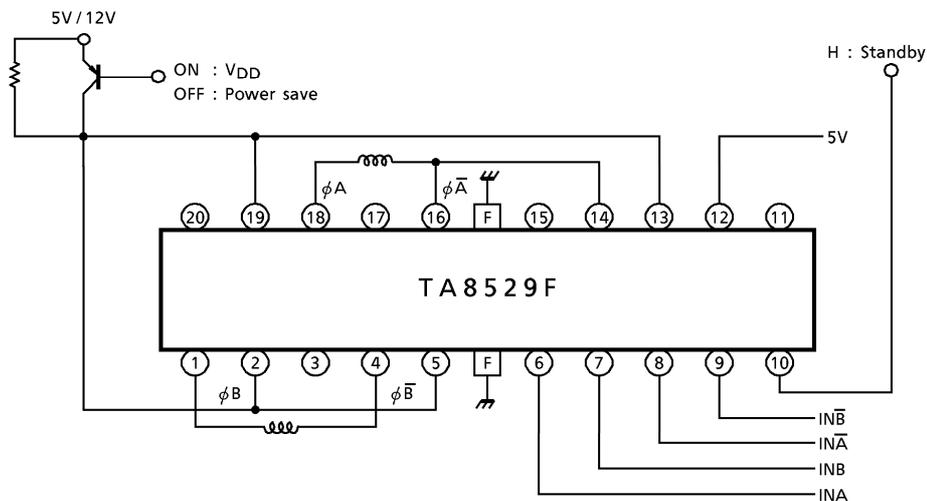
1. Four-input method



2. Two-input method

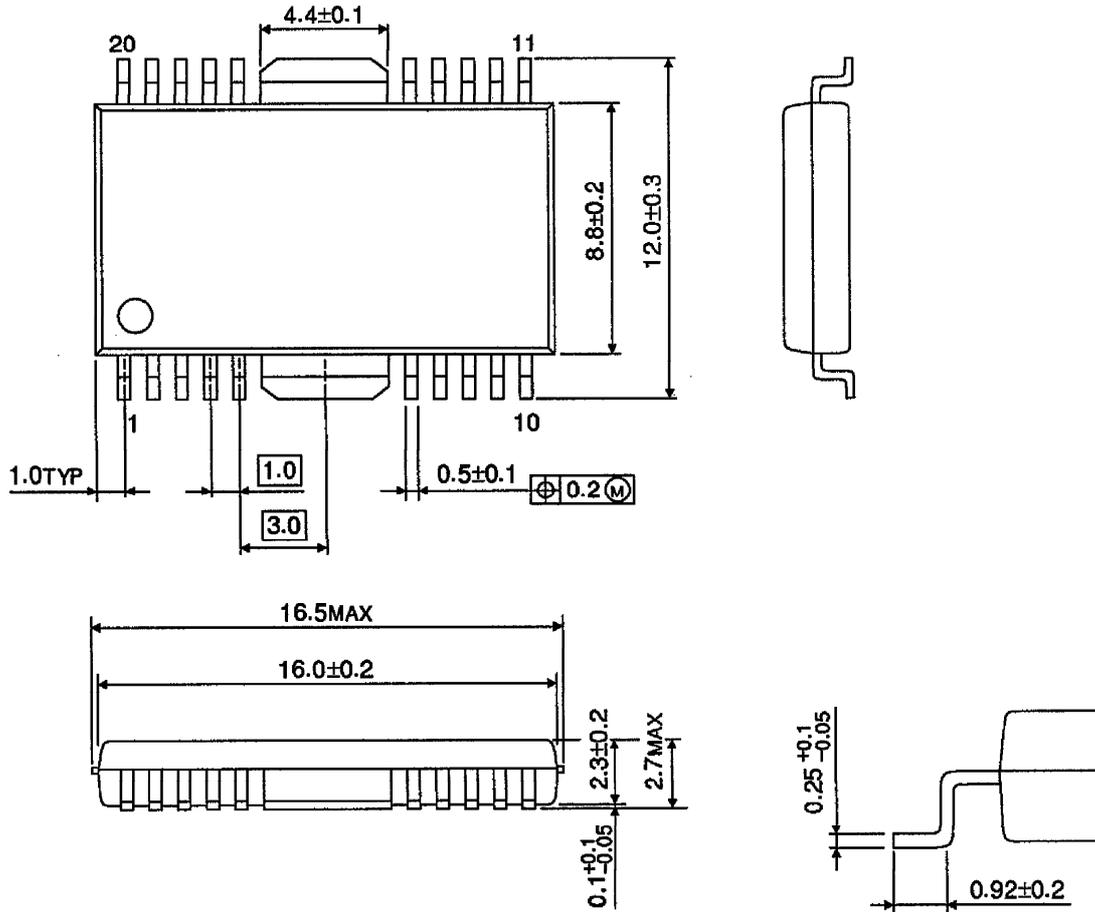


3. Power save application circuit



PACKAGE DRAWING
HSOP20-P-450-1.00

Unit : mm



Weight : 0.79g (Typ.)